

N-Channel 80-V (D-S) MOSFET

Key Features:

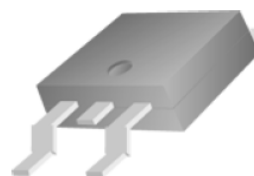
- Low $r_{DS(on)}$ trench technology
- Low thermal impedance
- Fast switching speed

Typical Applications:

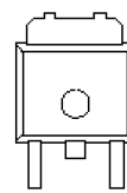
- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits



RoHS
COMPLIANT
HALOGEN
FREE



TO-252



G D S

Top View

PRODUCT SUMMARY		
V_{DS} (V)	$r_{DS(on)}$ (m Ω)	I_D (A)
80	11 @ $V_{GS} = 10V$	55
	13 @ $V_{GS} = 4.5V$	51

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V_{DS}	80	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current ^a	I_D	55	A
Pulsed Drain Current ^b	I_{DM}	200	
Continuous Source Current (Diode Conduction) ^a	I_S	55	A
Power Dissipation ^a	P_D	50	W
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55 to 175	$^\circ C$

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	40	$^\circ C/W$
Maximum Junction-to-Case	$R_{\theta JC}$	3	

Notes

- Package Limited
- Pulse width limited by maximum junction temperature

Electrical Characteristics

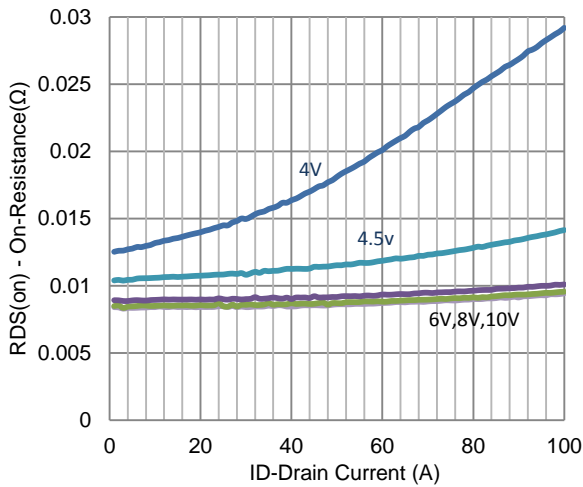
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 64 V, V_{GS} = 0 V$			1	uA
		$V_{DS} = 64 V, V_{GS} = 0 V, T_J = 55^\circ C$			25	
On-State Drain Current	$I_{D(on)}$	$V_{DS} = 5 V, V_{GS} = 10 V$	27.5			A
Drain-Source On-Resistance	$r_{DS(on)}$	$V_{GS} = 10 V, I_D = 27.5 A$			11	m Ω
		$V_{GS} = 4.5 V, I_D = 25.3 A$			13	
Forward Transconductance	g_{fs}	$V_{DS} = 15 V, I_D = 27.5 A$		35		S
Diode Forward Voltage	V_{SD}	$I_S = 27 A, V_{GS} = 0 V$		0.82		V
Dynamic						
Total Gate Charge	Q_g	$V_{DS} = 40 V, V_{GS} = 4.5 V, I_D = 20 A$		58		nC
Gate-Source Charge	Q_{gs}			14		
Gate-Drain Charge	Q_{gd}			39		
Turn-On Delay Time	$t_{d(on)}$	$V_{DS} = 40 V, R_L = 2 \Omega, I_D = 20 A,$ $V_{GEN} = 10 V, R_{GEN} = 6 \Omega$		19		ns
Rise Time	t_r			45		
Turn-Off Delay Time	$t_{d(off)}$			178		
Fall Time	t_f			62		
Input Capacitance	C_{iss}	$V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz$		5052		pF
Output Capacitance	C_{oss}			471		
Reverse Transfer Capacitance	C_{rss}			446		

Notes

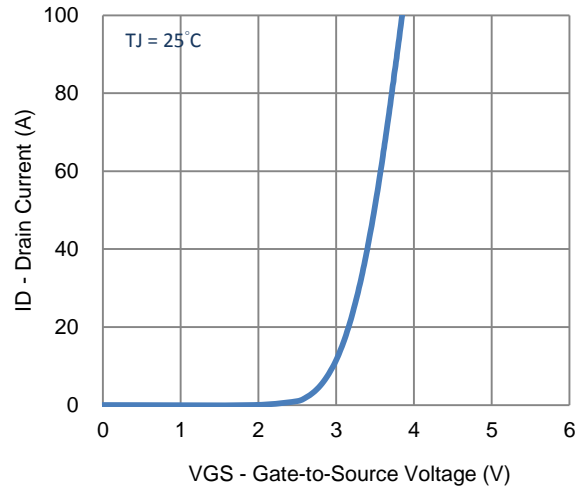
- Pulse test: PW \leq 300us duty cycle \leq 2%.
- Guaranteed by design, not subject to production testing.

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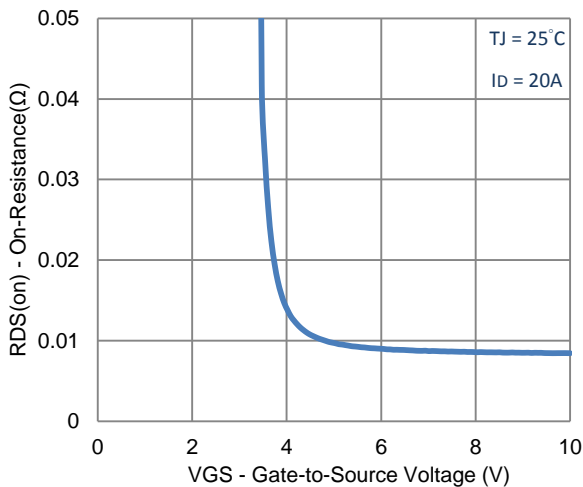
Typical Electrical Characteristics



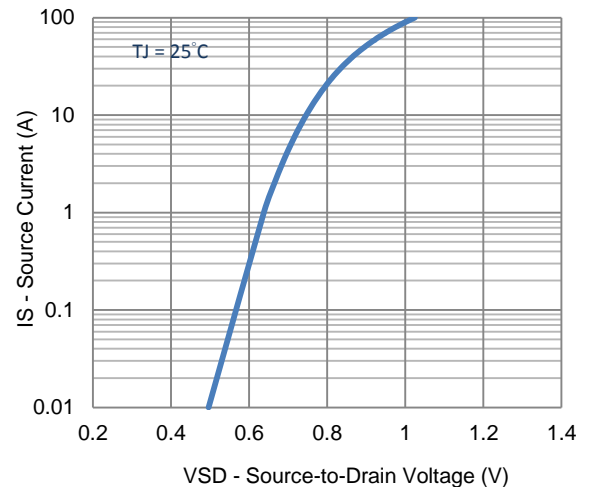
1. On-Resistance vs. Drain Current



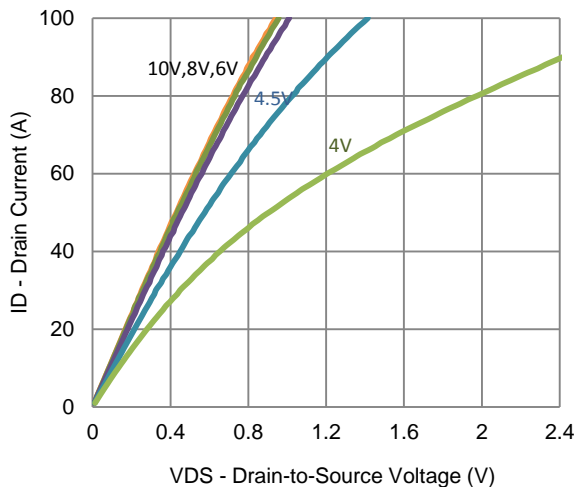
2. Transfer Characteristics



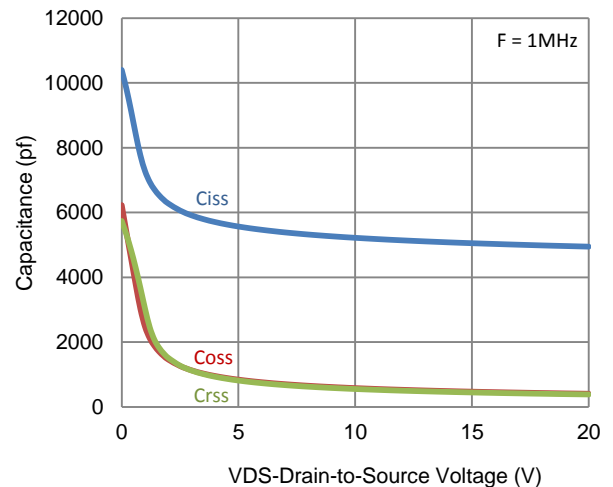
3. On-Resistance vs. Gate-to-Source Voltage



4. Drain-to-Source Forward Voltage

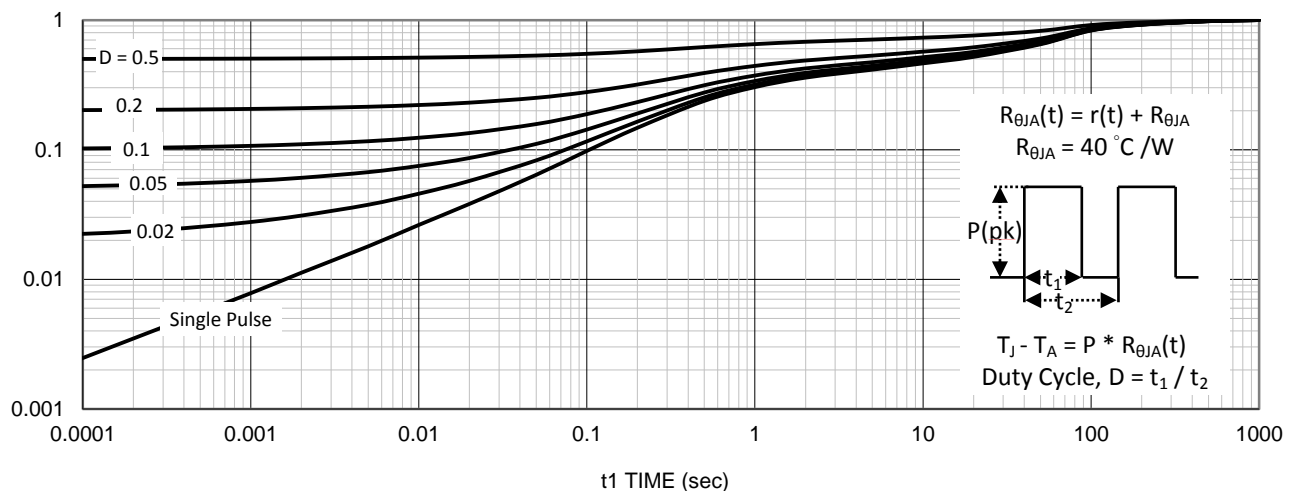
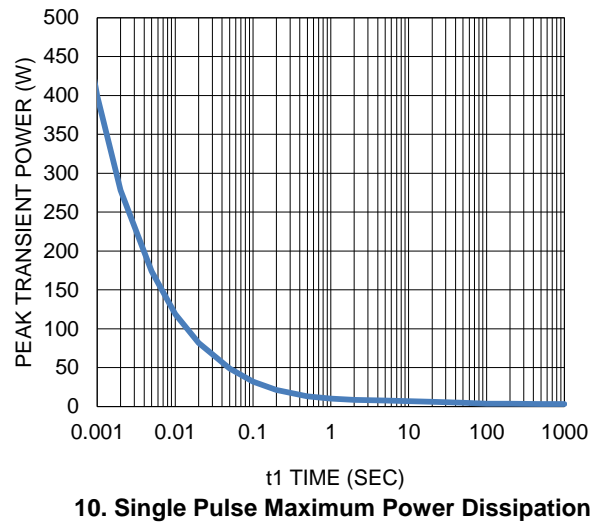
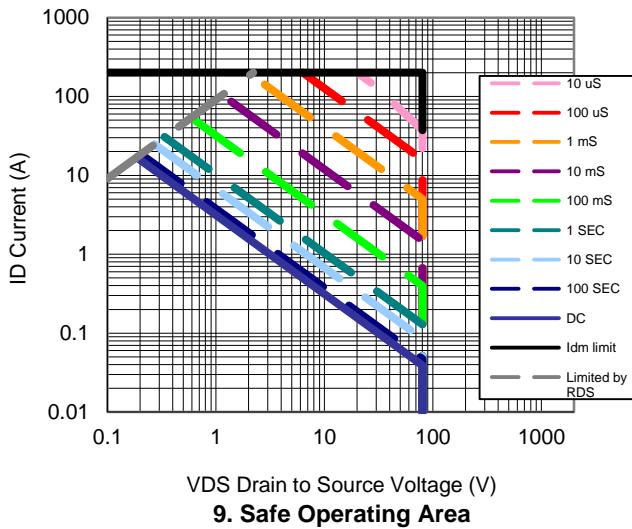
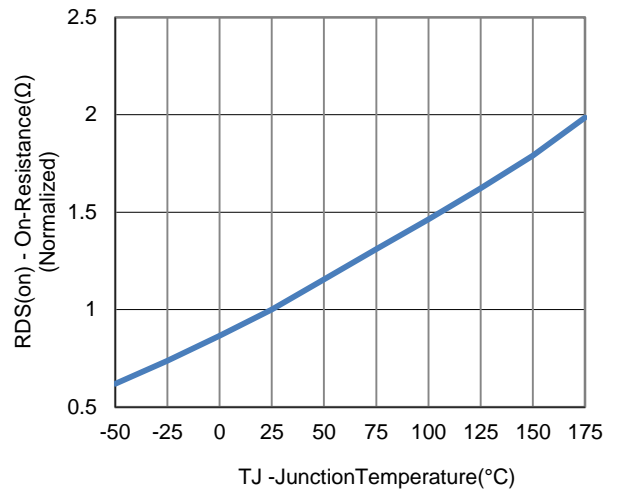
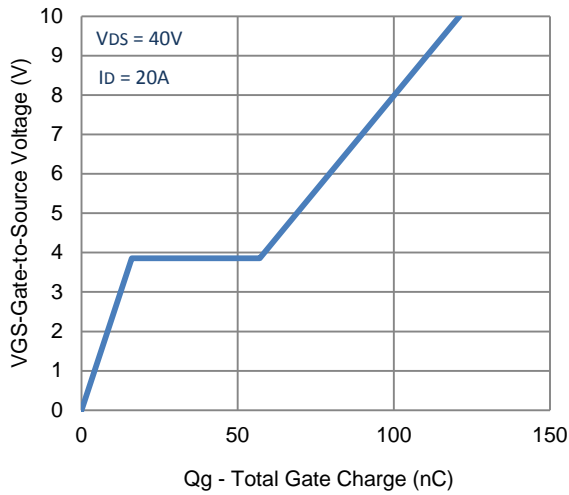


5. Output Characteristics

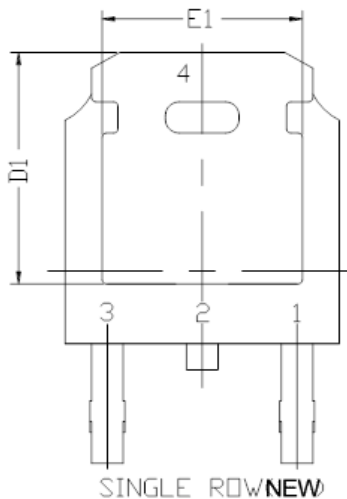
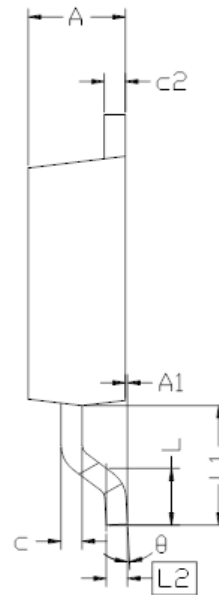
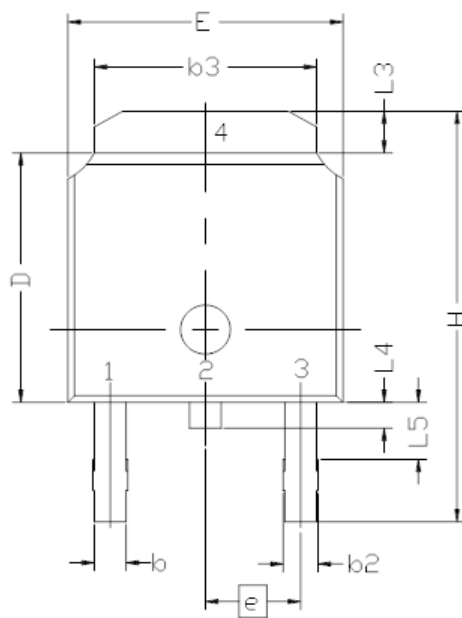


6. Capacitance

Typical Electrical Characteristics



Package Information



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2.743 REF		
L2	0.508 BSC		
L3	0.89	--	1.27
L4	0.64	--	1.01
L5	--	--	--
D	6.00	6.10	6.223
H	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	5.21	5.34	5.46
e	2.286 BSC		
A	2.20	2.30	2.38
A1	0	--	0.127
c	0.45	0.50	0.60
c2	0.45	0.50	0.58
D1	5.30	--	--
E1	4.40	--	--
θ	0°	--	10°

Note:

1. All Dimension Are In mm.
2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.